SUPERCONDUCTIVITY AND VACANCY STRUCTURES OF THE PRESSURE-INDUCED NaCI-TYPE PHASES OF THE In-Te SYSTEM

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(Received 23 December 1963)

We have found that a solid-solution range of Te exists in the pressure-induced NaCl-type InTe. The compounds are actually deficient in In; the formulas may be written ${\rm In}_{1-x}$ Te, with $0 \le x \le 0.18$. As far as we know, this is the first time structures with a substantial number of vacancies have been produced at high pressures. Superconductivity exists in the whole range of composition, the transition temperatures $T_{\rm c}$ decreasing with In/Te ratio, from 3.45-3.20°K for InTe to 1.06-1.02°K for ${\rm In}_{0.82}{\rm Te}$; the lattice constant decreases from 6.16 to 6.052 Å (see Table I and Fig. 1). An explanation

CONTENT ANALYSIS

A. InTe E

B. superconductivity

B. phase transitions,
effects of pressure
on

of the metallic behavior of these compounds has been deduced and appears also to account for the behavior of $T_{\rm c}$ with ${\rm In}/{\rm Te}$ ratio.

Normal InTe undergoes transformation at 30 kbar to the NaCl-type phase 1 which is retained metastably at atmospheric pressure and room temperature. This phase was first reported to be superconducting at 2.18°K by Bömmel and others 2 but later Banus and others 1 reported a significantly higher transition temperature 3.7-3.5°K. Our result for InTe is in better agreement with the higher value.

We became interested in the NaCl-type phase when it occurred in some high pressure-high temperature experiments on ${\rm In_2Te_3}$ and had a lattice constant of 6.052 Å, considerably smaller than that of stoichiometric InTe. Consequently several compositions in the range 33.3 to 55.0 at. % Te were prepared by melting together appropriate amounts of 99.99+ In and Te in sealed evacuated fused silica tubes which were continually agitated to ensure intimate mixing. X-ray powder photographs (CuK radiation) gave the expected patterns for normal ${\rm In_2Te}$ and ${\rm InTe}$. For compositions with ${\rm In/Te} \le 1$, mixtures of InTe and ${\rm In_2Te}_3$ resulted as would be predicted

Table I. Superconducting Transition Temperatures T_c and Lattice Constants a for \ln_{1-x} Te Compounds with NaCl-like Structure.

1-x	T _c (°K)	a (Å)
1.00	3.45 - 3.2	6.16 ± 0.01
0.95	2.7 - 2.5	6.14
0.91	2.04 - 1.87	6.110 ± 0.003
0.87	1.55 - 1.40	6.081
0.83	1.15 - 1.09	6.055
0.82	1.06 - 1.02	6.052

from the reported³ phase diagram. Pressure was generated in a piston cylinder device. The furnace assembly was the same as that described earlier;⁴ the sample container was a tantalum cup with a boron nitride cover. Pressure of about 30 kbar was applied first and the temperature raised to about 800°C. After a few minutes, the temperature was reduced to ambient in about 5 min and the pressure released. In experiments below the melting temperature, the specimens were kept under pressure at 550°C for about one hour.

After being subjected to compression and heating, all specimens yielded metastably retainable NaCl-type phases. In the composition range InTe to InTe_{1.22}, single phases were obtained; In₂Te, however, transformed to a mixture of In and stoichiometric InTe, indicating (contrary to ref 1) that this phase does not dissolve excess In. The same results were obtained whether or not the specimens were melted.

The density of the NaCl-like In_{0.82}Te, determined pycnometrically, was 6.72 g/cc, which implies the formula (In_{0.83}Te_{0.01}D_{0.16})Te; that is, each unit cell contains an average of 3.32 In, 0.04 Te and 0.64 vacancies in In sites. X-ray diffraction data give a clear corroboration of the vacancy structures. Because the difference in scattering by In and Te atoms is small, the {111} line of InTe is very faint, but, as in the case of AgSbTe25 (and contrary to refs 1 and 2), can be seen. As In/Te decreases, the intensities of the odd-index reflections increase relative to the even-index ones. For In 0.82 Te, the {111}, {311}, and {331} reflections are readily seen. Weissenberg and Buerger precession camera photographs of a single crystal of In_{0.82}Te corroborate the (statistical⁵) cubicity of this phase.

Tests for superconductivity on powdered specimens were made by the alternating current method of Schawlow and Devlin. ⁶

We propose that the crystal structure of the highpressure form of InTe is a disordered one (like that of AgSbTe25) containing equal numbers of In and In 3+ ions, and that its metallic behavior results from the ease with which electron transfer can occur from In to In 3 ions throughout the crystal. Normal InTe (ref 7) has the TISe (ref 8) structure and is a semiconductor. The TISe crystal is ordered and contains equal numbers of T1+ and T13+ ions in 8 and 4 coordination respectively; consequently, it is expected that In + and In 3+ ions are arranged similarly in normal InTe. The structure stabilizes the In valencies because it is energetically unfavorable for an In in 8 coordination to be trivalent or one in a tetrahedral site to be monovalent. The compound AgSbTe 2 5 is isostructural with the pressure-induced form of InTe; Ag + and Sb 3 + ions have 6 coordination and their average valence is that of Te. In AgSbTe, transfer of electrons from Ag to Sb is also energetically unfavorable because the +1 valence state of Ag is highly stable; this compound is also a semiconductor.

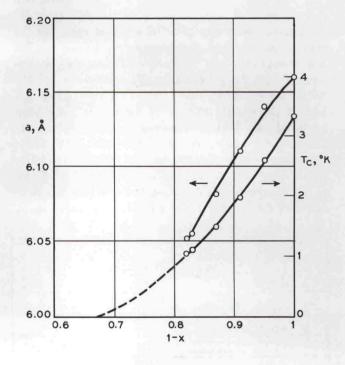


Fig. 1. Lattice constant a and superconducting transition temperature $T_{\rm c}$ vs (1-x) for the system $\ln_{1-x} {\rm Te}$.